

QL4036 - QuickRAM™



36,000 Usable PLD Gate QuickRAM ESP Combining Performance, Density, and Embedded RAM

DEVICE HIGHLIGHTS

High Performance & High Density

- 36,000 Usable PLD Gates with 204 I/Os
- 300 MHz 16-bit Counters, 400 MHz Datapaths, 160+ MHz FIFOs
- 0.35µm four-layer metal non-volatile CMOS process for smallest die sizes

High Speed Embedded SRAM

- 14 dual-port RAM modules, organized in user-configurable 1,152 bit blocks
- 5ns access times, each port independently accessible
- Fast and efficient for FIFO, RAM, and ROM functions

Easy to Use / Fast Development Cycles

- 100% routable with 100% utilization and complete pin-out stability
- Variable-grain logic cells provide high performance and 100% utilization
- Comprehensive design tools include high quality Verilog/VHDL synthesis

Advanced I/O Capabilities

- Interfaces with both 3.3V and 5.0V devices
- PCI compliant with 3.3V and 5.0V busses for -1/-2/-3/-4 speed grades
- Full JTAG boundary scan
- Registered I/O cells with individually controlled clocks and output enables

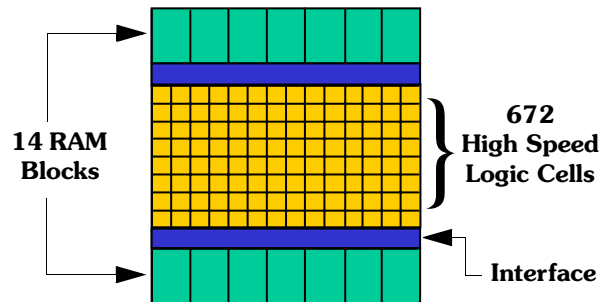


FIGURE 1. QuickRAM Block Diagram

ARCHITECTURE OVERVIEW

The QuickRAM family of ESPs (Embedded Standard Products) offers FPGA logic in combination with Dual-Port SRAM modules. The QL4036 is a 36,000 usable PLD gate member of the QuickRAM family of ESPs. QuickRAM ESPs are fabricated on a 0.35µm four-layer metal process using QuickLogic's patented ViaLink™ technology to provide a unique combination of high performance, high density, low cost, and extreme ease-of-use.

The QL4036 contains 672 logic cells and 14 dual port RAM modules (see Figure 1). Each RAM module has 1,152 RAM bits, for a total of 16,128 bits. RAM Modules are Dual Port (one read port, one write port) and can be configured into one of four modes: 64 (deep) x18 (wide), 128x9, 256x4, or 512x2 (see Figure 2). With a maximum of 204 I/Os, the QL4036 is available in 144-pin TQFP, 208-pin PQFP and 256-pin PBGA packages.

Designers can cascade multiple RAM modules to increase the depth or width allowed in single modules by connecting corresponding address lines together and dividing the words between modules (see Figure 3). This approach allows up to 512-deep configurations as large as 16 bits wide in the smallest QuickRAM device and 44 bits wide in the largest device.



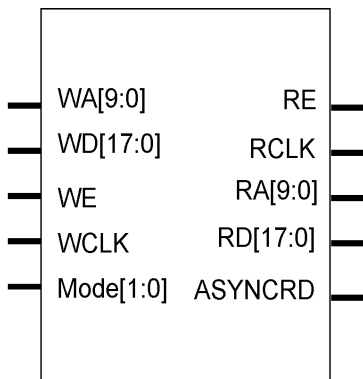


FIGURE 2. QuickRAM Module

Software support for the complete QuickRAM family, including the QL4016, is available through two basic packages. The turnkey QuickWorks™ package provides the most complete ESP software solution from design entry to logic synthesis, to place and route, to simulation. The QuickTools™ packages provides a solution for designers who use Cadence, Exemplar, Mentor, Syn-opsys, Synplicity, Viewlogic, Veribest, or other third-party tools for design entry, synthesis, or simulation.

The QuickLogic variable grain logic cell features up to 16 simultaneous inputs and 5 outs within a cell that can be fragmented into 5 independent cells. Each cell has a fan-in of 29 including register and control lines (see Figure 4).

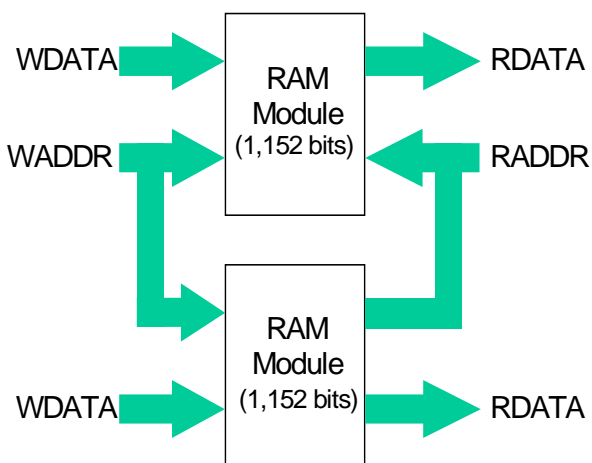


FIGURE 3. QuickRAM Module bits

PRODUCT SUMMARY

Total of 204 I/O Pins

- 196 bi-directional input/output pins, PCI-compliant for 5.0 volt and 3.3 volt buses for -1/-2/-3/-4 speed grades
- 8 high-drive input/distributed network pins

Eight Low-Skew Distributed Networks

- Two array clock/control networks available to the logic cell flip-flop clock, set and reset inputs - each driven by and input-only pin
- Six global clock/control networks available to the logic cell F1, clock, set and reset inputs and the input and I/O register clock, reset and enable inputs as well as the output enable control - each driven by an input-only or I/O pin, or any logic cell output or I/O cell feedback

High Performance

- Input + logic cell + output total delays under 6 ns
- Data path speeds over 400 MHz
- Counter speeds over 300 MHz
- FIFO speeds over 160+ MHz

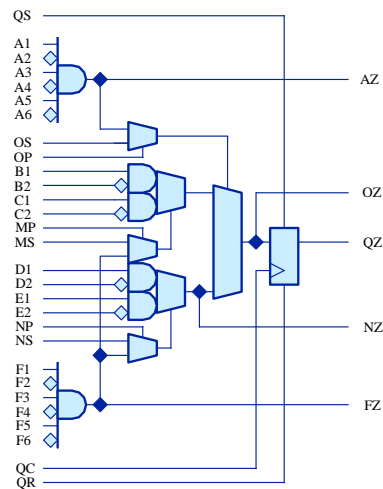
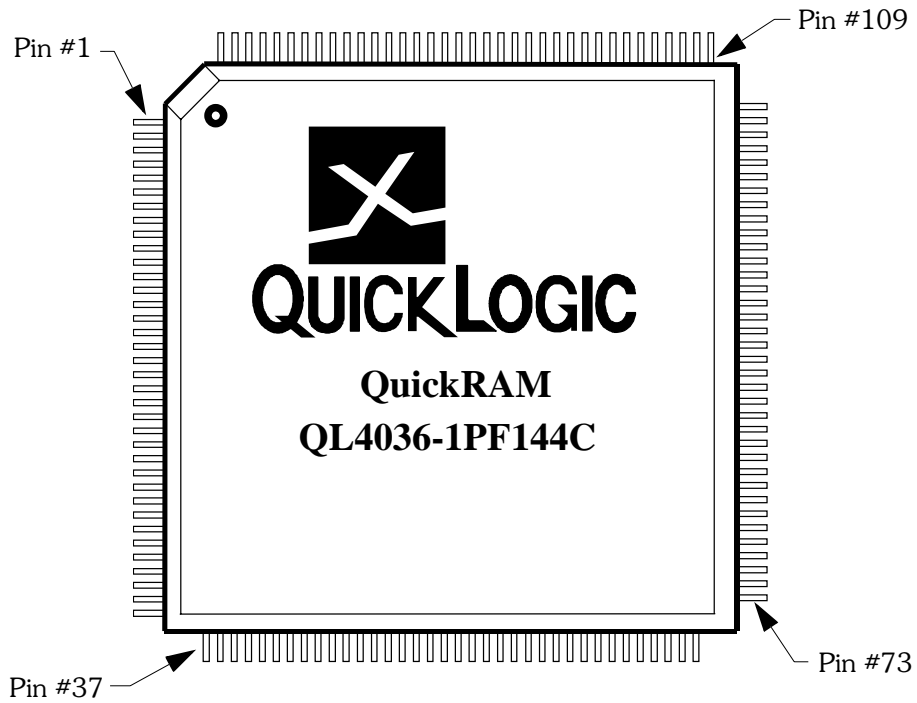
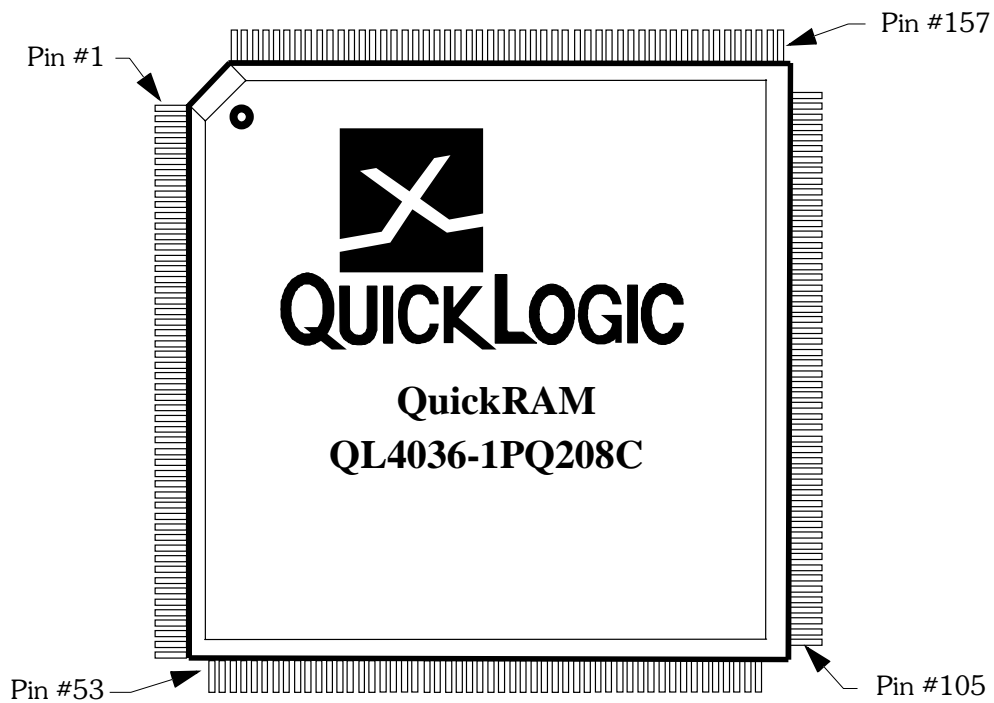


FIGURE 4. Logic Cell

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**144 Pin TQFP
Pinout Diagram**



**208 Pin PQFP/CQFP
Pinout Diagram**

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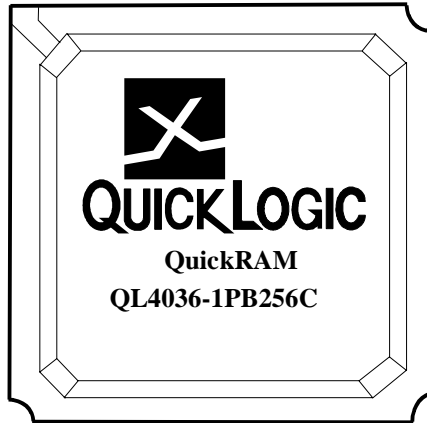
208 PQFP & 144 TQFP PINOUT TABLE

208 PQFP	144 TQFP	Function	208 PQFP	144 TQFP	Function	208 PQFP	144 TQFP	Function	208 PQFP	144 TQFP	Function	208 PQFP	144 TQFP	Function
1	NC	I/O	43	30	GND	85	60	I/O	127	87	GND	169	117	I/O
2	1	I/O	44	31	I/O	86	61	I/O	128	88	I/O	170	118	I/O
3	2	I/O	45	NC	I/O	87	NC	I/O	129	89	GCLK / I	171	119	I/O
4	3	I/O	46	32	I/O	88	62	I/O	130	90	ACLK / I	172	120	I/O
5	NC	I/O	47	NC	I/O	89	63	I/O	131	91	VCC	173	NC	I/O
6	4	I/O	48	33	I/O	90	NC	I/O	132	92	GCLK / I	174	NC	I/O
7	5	I/O	49	NC	I/O	91	NC	I/O	133	93	GCLK / I	175	121	I/O
8	NC	I/O	50	34	I/O	92	64	I/O	134	94	VCC	176	NC	I/O
9	6	I/O	51	35	I/O	93	NC	I/O	135	95	I/O	177	122	GND
10	7	VCC	52	36	I/O	94	65	I/O	136	NC	I/O	178	123	I/O
11	NC	I/O	53	37	I/O	95	66	GND	137	96	I/O	179	124	I/O
12	NC	GND	54	38	TDI	96	67	I/O	138	NC	I/O	180	NC	I/O
13	8	I/O	55	39	I/O	97	NC	VCC	139	97	I/O	181	125	I/O
14	NC	I/O	56	NC	I/O	98	NC	I/O	140	98	I/O	182	126	GND
15	9	I/O	57	40	I/O	99	68	I/O	141	NC	I/O	183	127	I/O
16	NC	I/O	58	NC	I/O	100	69	I/O	142	99	I/O	184	128	I/O
17	10	I/O	59	NC	GND	101	NC	I/O	143	NC	I/O	185	129	I/O
18	11	I/O	60	41	I/O	102	70	I/O	144	100	I/O	186	NC	I/O
19	12	I/O	61	42	VCC	103	71	TRSTB	145	NC	VCC	187	130	VCCIO
20	13	I/O	62	43	I/O	104	72	TMS	146	101	I/O	188	131	I/O
21	NC	I/O	63	NC	I/O	105	NC	I/O	147	102	GND	189	132	I/O
22	14	I/O	64	44	I/O	106	73	I/O	148	103	I/O	190	NC	I/O
23	15	GND	65	45	I/O	107	NC	I/O	149	104	I/O	191	133	I/O
24	16	I/O	66	NC	I/O	108	74	I/O	150	NC	I/O	192	134	I/O
25	17	GCLK / I	67	46	I/O	109	75	I/O	151	105	I/O	193	NC	I/O
26	18	ACLK / I	68	47	I/O	110	76	I/O	152	106	I/O	194	135	I/O
27	19	VCC	69	48	I/O	111	77	I/O	153	NC	I/O	195	136	I/O
28	20	GCLK / I	70	NC	I/O	112	NC	I/O	154	107	I/O	196	NC	I/O
29	21	GCLK / I	71	49	I/O	113	78	I/O	155	NC	I/O	197	137	I/O
30	22	VCC	72	NC	I/O	114	79	VCC	156	108	I/O	198	NC	I/O
31	23	I/O	73	50	GND	115	80	I/O	157	109	TCK	199	138	GND
32	NC	I/O	74	51	I/O	116	NC	GND	158	110	STM	200	139	I/O
33	24	I/O	75	52	I/O	117	81	I/O	159	111	I/O	201	NC	VCC
34	NC	I/O	76	NC	I/O	118	82	I/O	160	NC	I/O	202	140	I/O
35	25	I/O	77	53	I/O	119	NC	I/O	161	112	I/O	203	NC	I/O
36	NC	I/O	78	54	GND	120	83	I/O	162	113	I/O	204	141	I/O
37	26	I/O	79	55	I/O	121	NC	I/O	163	NC	GND	205	142	I/O
38	27	I/O	80	56	I/O	122	84	I/O	164	NC	I/O	206	NC	I/O
39	28	I/O	81	NC	I/O	123	85	I/O	165	114	VCC	207	143	TDO
40	NC	I/O	82	57	I/O	124	NC	I/O	166	115	I/O	208	144	I/O
41	NC	VCC	83	58	VCCIO	125	86	I/O	167	116	I/O			
42	29	I/O	84	59	I/O	126	NC	I/O	168	NC	I/O			

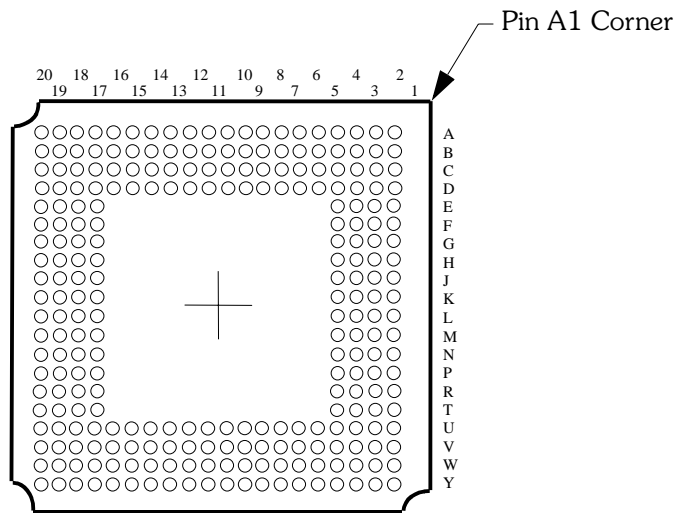
TABLE 1: 208 PQFP and 144 TQFP Pinout Table

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PINOUT DIAGRAM



**256 Pin PBGA
TOP**



Bottom

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PBGA 256 PINOUT TABLE

256 PBGA	Function	256 PBGA	Function	256 PBGA	Function	256 PBGA	Function	256 PBGA	Function	256 PBGA	Function
A1	VSS	C4	I/O	E19	I/O	L2	ACLK / I	T17	I/O	V20	I/O
A2	I/O	C5	I/O	E20	I/O	L3	GCLK / I	T18	I/O	W1	I/O
A3	I/O	C6	I/O	F1	I/O	L4	GCLK / I	T19	NC	W2	I/O
A4	I/O	C7	I/O	F2	I/O	L17	VCC	T20	I/O	W3	TDI
A5	I/O	C8	I/O	F3	I/O	L18	I/O	U1	I/O	W4	I/O
A6	I/O	C9	VCCIO	F4	VCC	L19	I/O	U2	I/O	W5	I/O
A7	I/O	C10	I/O	F17	VCC	L20	I/O	U3	I/O	W6	I/O
A8	I/O	C11	I/O	F18	NC	M1	I/O	U4	VSS	W7	I/O
A9	I/O	C12	I/O	F19	I/O	M2	I/O	U5	I/O	W8	I/O
A10	I/O	C13	I/O	F20	I/O	M3	I/O	U6	VCC	W9	I/O
A11	I/O	C14	I/O	G1	I/O	M4	NC	U7	I/O	W10	I/O
A12	I/O	C15	I/O	G2	NC	M17	NC	U8	VSS	W11	I/O
A13	I/O	C16	I/O	G3	I/O	M18	I/O	U9	I/O	W12	I/O
A14	I/O	C17	I/O	G4	I/O	M19	I/O	U10	VCC	W13	I/O
A15	I/O	C18	I/O	G17	I/O	M20	I/O	U11	I/O	W14	I/O
A16	I/O	C19	I/O	G18	I/O	N1	I/O	U12	I/O	W15	I/O
A17	I/O	C20	I/O	G19	NC	N2	I/O	U13	VSS	W16	I/O
A18	I/O	D1	I/O	G20	I/O	N3	I/O	U14	I/O	W17	I/O
A19	TCK	D2	I/O	H1	I/O	N4	VSS	U15	VCC	W18	I/O
A20	I/O	D3	I/O	H2	I/O	N17	VSS	U16	I/O	W19	I/O
B1	TDO	D4	VSS	H3	I/O	N18	I/O	U17	VSS	W20	TRSTB
B2	I/O	D5	I/O	H4	VSS	N19	I/O	U18	I/O	Y1	I/O
B3	I/O	D6	VCC	H17	VSS	N20	I/O	U19	I/O	Y2	NC
B4	I/O	D7	I/O	H18	I/O	P1	I/O	U20	I/O	Y3	I/O
B5	I/O	D8	VSS	H19	I/O	P2	I/O	V1	I/O	Y4	I/O
B6	I/O	D9	I/O	H20	I/O	P3	I/O	V2	NC	Y5	I/O
B7	I/O	D10	I/O	J1	I/O	P4	I/O	V3	I/O	Y6	I/O
B8	I/O	D11	VCC	J2	I/O	P17	I/O	V4	I/O	Y7	I/O
B9	I/O	D12	I/O	J3	NC	P18	I/O	V5	I/O	Y8	I/O
B10	I/O	D13	VSS	J4	I/O	P19	NC	V6	I/O	Y9	I/O
B11	I/O	D14	I/O	J17	NC	P20	I/O	V7	I/O	Y10	I/O
B12	I/O	D15	VCC	J18	I/O	R1	NC	V8	I/O	Y11	I/O
B13	I/O	D16	I/O	J19	I/O	R2	I/O	V9	I/O	Y12	I/O
B14	I/O	D17	VSS	J20	GCLK / I	R3	I/O	V10	I/O	Y13	I/O
B15	I/O	D18	I/O	K1	I/O	R4	VCC	V11	I/O	Y14	I/O
B16	I/O	D19	I/O	K2	I/O	R17	VCC	V12	VCCIO	Y15	I/O
B17	NC	D20	I/O	K3	I/O	R18	I/O	V13	I/O	Y16	I/O
B18	STM	E1	NC	K4	VCC	R19	I/O	V14	I/O	Y17	I/O
B19	NC	E2	I/O	K17	GCLK / I	R20	I/O	V15	I/O	Y18	I/O
B20	I/O	E3	I/O	K18	ACLK / I	T1	NC	V16	I/O	Y19	I/O
C1	I/O	E4	I/O	K19	GCLK / I	T2	I/O	V17	I/O	Y20	NC
C2	I/O	E17	I/O	K20	NC	T3	I/O	V18	I/O		
C3	I/O	E18	I/O	L1	GCLK / I	T4	NC	V19	TMS		

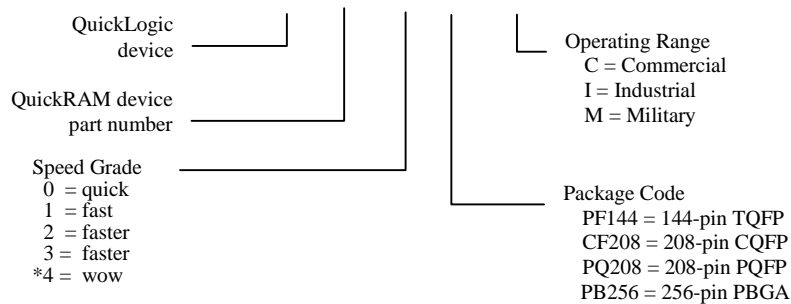
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PIN DESCRIPTION

Pin	Function	Description
TDI/RSI	Test Data In for JTAG / RAM init. Serial Data In	Hold HIGH during normal operation. Connects to serial PROM data in for RAM initialization. Connect to VCC if unused.
TRSTB/RRO	Active low Reset for JTAG / RAM init. reset out	Hold LOW during normal operation. Connects to serial PROM reset for RAM initialization. Connect to GND if unused.
TMS	Test Mode Select for JTAG	Hold HIGH during normal operation. Connect to VCC if not used for JTAG.
TCK	Test Clock for JTAG	Hold HIGH or LOW during normal operation. Connect to VCC or ground if not used for JTAG.
TDO/RCO	Test data out for JTAG / RAM init. clock out	Connect to serial PROM clock for RAM initialization. Must be left unconnected if not used for JTAG or RAM initialization.
STM	Special Test Mode	Must be grounded during normal operation.
I/ACLK	High-drive input and/or array network driver	Can be configured as either or both.
I/GCLK	High-drive input and/or global network driver	Can be configured as either or both.
I	High-drive input	Use for input signals with high fanout.
I/O	Input/Output pin	Can be configured as an input and/or output.
VCC	Power supply pin	Connect to 3.3V supply.
VCCIO	Input voltage tolerance pin	Connect to 5.0 volt supply if 5 volt input tolerance is required, otherwise connect to 3.3V supply.
GND	Ground pin	Connect to ground.
GND/THERM	Ground/Thermal pin	Available on 456-PBGA only. Connect to ground plane on PCB if heat sinking desired. Otherwise may be left unconnected.

Ordering Information

QL 4036 - 1 PQ208 C



* Contact QuickLogic regarding availability.

QL4036 - QuickRAM™

Absolute Maximum Ratings

VCC Voltage.....	-0.5 to 4.6V	DC Input Current.....	±20 mA
VCCIO Voltage	-0.5 to 7.0V	ESD Pad Protection	±2000V
Input Voltage	-0.5 to VCCIO+0.5V	Storage Temperature	-65°C to +150°C
Latch-up Immunity	±200mA	Lead Temperature	300°C

Operating Range

Symbol	Parameter	Military		Industrial		Commercial		Unit	
		Min	Max	Min	Max	Min	Max		
VCC	Supply Voltage	3.0	3.6	3.0	3.6	3.0	3.6	V	
VCCIO	I/O Input Tolerance Voltage	3.0	5.5	3.0	5.5	3.0	5.25	V	
TA	Ambient Temperature	-55		-40	85	0	70	°C	
TC	Case Temperature		125					°C	
K	Delay Factor	-0 Speed Grade	0.42	2.03	0.43	1.90	0.46	1.85	
		-1 Speed Grade	0.42	1.64	0.43	1.54	0.46	1.50	
		-2 Speed Grade	0.42	1.37	0.43	1.28	0.46	1.25	
		-3 Speed Grade	N/A	N/A	0.43	0.90	0.46	0.88	
		-4 Speed Grade	N/A	N/A	0.43	0.82	0.46	0.80	

DC Characteristics

Symbol	Parameter	Conditions	Min	Max	Unit
VIH	Input HIGH Voltage		0.5VCC	VCCIO+0.5	V
VIL	Input LOW Voltage		-0.5	0.3VCC	V
VOH	Output HIGH Voltage	IOH = -12 mA	2.4		V
		IOH = -500 µA	0.9VCC		V
VOL	Output LOW Voltage	IOL = 16 mA [1]		0.45	V
		IOL = 1.5 mA		0.1VCC	V
II	I or I/O Input Leakage Current	VI = VCCIO or GND	-10	10	µA
IOZ	3-State Output Leakage Current	VI = VCCIO or GND	-10	10	µA
CI	Input Capacitance [2]			10	pF
IOS	Output Short Circuit Current [3]	VO = GND	-15	-180	mA
		VO = VCC	40	210	mA
ICC	D.C. Supply Current [4]	VI, VIO = VCCIO or GND	0.50 (typ)	2	mA
ICCIO	D.C. Supply Current on VCCIO		0	100	µA

Notes:

[1] Applies only to -1/-2/-3/-4 commercial grade devices. These speed grades are also PCI-compliant. All other devices have 8 mA IOL specifications.

[2]Capacitance is sample tested only. Clock pins are 12 pF maximum.

[3]Only one output at a time. Duration should not exceed 30 seconds.

[4]For -1/-2/-3/-4 commercial grade devices only. Maximum ICC is 3 mA for -0 commercial grade and all industrial grade devices, and 5 mA for all military grade devices. For AC conditions, contact QuickLogic customer engineering.

AC CHARACTERISTICS at VCC = 3.3V, TA = 25°C (K = 1.00)

(To calculate delays, multiply the appropriate K factor in the "Operating Range" section by the following numbers.)

Logic Cells

Symbol	Parameter	Propagation Delays (ns) Fanout [5]				
		1	2	3	4	8
tPD	Combinatorial Delay [6]	1.4	1.7	1.9	2.2	3.2
tSU	Setup Time [6]	1.7	1.7	1.7	1.7	1.7
tH	Hold Time	0.0	0.0	0.0	0.0	0.0
tCLK	Clock to Q Delay	0.7	1.0	1.2	1.5	2.5
tCWHI	Clock High Time	1.2	1.2	1.2	1.2	1.2
tCWLO	Clock Low Time	1.2	1.2	1.2	1.2	1.2
tSET	Set Delay	1.0	1.3	1.5	1.8	2.8
tRESET	Reset Delay	0.8	1.1	1.3	1.6	2.6
tSW	Set Width	1.9	1.9	1.9	1.9	1.9
tRW	Reset Width	1.8	1.8	1.8	1.8	1.8

RAM Cell Synchronous Write Timing

Symbol	Parameter	Propagation Delays (ns) Fanout				
		1	2	3	4	8
TSWA	WA Setup Time to WCLK	1.0	1.0	1.0	1.0	1.0
THWA	WA Hold Time to WCLK	0.0	0.0	0.0	0.0	0.0
TSWD	WD Setup Time to WCLK	1.0	1.0	1.0	1.0	1.0
THWD	WD Hold Time to WCLK	0.0	0.0	0.0	0.0	0.0
TSWE	WE Setup Time to WCLK	1.0	1.0	1.0	1.0	1.0
THWE	WE Hold Time to WCLK	0.0	0.0	0.0	0.0	0.0
TWCRD	WCLK to RD (WA=RA) [5]	5.0	5.3	5.6	5.9	7.1

Notes:

[5] Stated timing for worst case Propagation Delay over process variation at VCC=3.3V and TA=25°C. Multiply by the appropriate Delay Factor, K, for speed grade, voltage and temperature settings as specified in the Operating Range.

[6] These limits are derived from a representative selection of the slowest paths through the QuickRAM logic cell including typical net delays. Worst case delay values for specific paths should be determined from timing analysis of your particular design.

RAM Cell Synchronous Read Timing

Symbol	Parameter	Propagation Delays (ns) Fanout				
		1	2	3	4	8
TSRA	RA Setup Time to RCLK	1.0	1.0	1.0	1.0	1.0
THRA	RA Hold Time to RCLK	0.0	0.0	0.0	0.0	0.0
TSRE	RE Setup Time to RCLK	1.0	1.0	1.0	1.0	1.0
THRE	RE Hold Time to RCLK	0.0	0.0	0.0	0.0	0.0
TRCRD	RCLK to RD [5]	4.0	4.3	4.6	4.9	6.1

RAM Cell Asynchronous Read Timing

Symbol	Parameter	Propagation Delays (ns) Fanout				
		1	2	3	4	8
RPDRD	RA to RD [5]	3.0	3.3	3.6	3.9	5.1

Input-Only/Clock Cells

Symbol	Parameter	Propagation Delays (ns) Fanout [5]						
		1	2	3	4	8	12	24
TIN	High Drive Input Delay	1.5	1.6	1.8	1.9	2.4	2.9	4.4
TINI	High Drive Input, Inverting Delay	1.6	1.7	1.9	2.0	2.5	3.0	4.5
TISU	Input Register Set-Up Time	3.1	3.1	3.1	3.1	3.1	3.1	3.1
TIH	Input Register Hold Time	0.0	0.0	0.0	0.0	0.0	0.0	0.0
TICLK	Input Register Clock To Q	0.7	0.8	1.0	1.1	1.6	2.1	3.6
TIRST	Input Register Reset Delay	0.6	0.7	0.9	1.0	1.5	2.0	3.5
TIESU	Input Register Clock Enable Setup Time	2.3	2.3	2.3	2.3	2.3	2.3	2.3
TIEH	Input Register Clock Enable Hold Time	0.0	0.0	0.0	0.0	0.0	0.0	0.0

Clock Cells

Symbol	Parameter	Propagation Delays (ns) Loads per Half Column [7]						
		1	2	3	4	8	10	11
tACK	Array Clock Delay	1.2	1.2	1.3	1.3	1.5	1.6	1.7
tGCKP	Global Clock Pin Delay	0.7	0.7	0.7	0.7	0.7	0.7	0.7
tGCKB	Global Clock Buffer Delay	0.8	0.8	0.9	0.9	1.1	1.2	1.3

Notes:

[7]The array distributed networks consist of 40 half columns and the global distributed networks consist of 44 half columns, each driven by an independent buffer. The number of half columns used does not affect clock buffer delay. The array clock has up to 8 loads per half column. The global clock has up to 11 loads per half column.

I/O Cell Input Delays

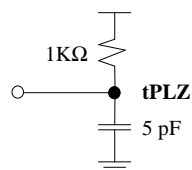
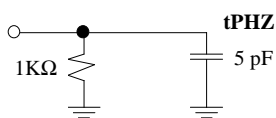
Symbol	Parameter	Propagation Delays (ns) Fanout [5]					
		1	2	3	4	8	10
tI/O	Input Delay (bidirectional pad)	1.3	1.6	1.8	2.1	3.1	3.6
TISU	Input Register Set-Up Time	3.1	3.1	3.1	3.1	3.1	3.1
TIH	Input Register Hold Time	0.0	0.0	0.0	0.0	0.0	0.0
TIOCLK	Input Register Clock To Q	0.7	1.0	1.2	1.5	2.5	3.0
TIORST	Input Register Reset Delay	0.6	0.9	1.1	1.4	2.4	2.9
TIESU	Input Register clock Enable Set-Up Time	2.3	2.3	2.3	2.3	2.3	2.3
TIEH	Input Register Clock Enable Hold Time	0.0	0.0	0.0	0.0	0.0	0.0

I/O Cell Output Delays

Symbol	Parameter	Propagation Delays (ns) Output Load Capacitance (pF)				
		30	50	75	100	150
TOUTLH	Output Delay Low to High	2.1	2.5	3.1	3.6	4.7
TOUTH	Output Delay High to Low	2.2	2.6	3.2	3.7	4.8
TPZH	Output Delay Tri-state to High	1.2	1.7	2.2	2.8	3.9
TPZL	Output Delay Tri-state to Low	1.6	2.0	2.6	3.1	4.2
TPHZ	Output Delay High to Tri-State [8]	2.0				
TPLZ	Output Delay Low to Tri-State [8]	1.2				

Notes:

[8]The following loads are used for tPXZ



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